

## DMTH45M5LPSWQ

40V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

### **Product Summary**

BV <sub>DSS</sub>	DSS RDS(ON) Max ID Max T <sub>C</sub> = +2	
40V	5.5mΩ @ V <sub>GS</sub> = 10V	86A
40 V	$7.9 { m m}\Omega @ { m V}_{ m GS} = 4.5 { m V}$	74A

## **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

PowerDI5060-8 (SWP) (Type UX)

- High frequency switching
- Synchronous rectifications
- DC-DC converters

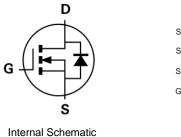
### **Features and Benefits**

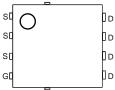
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low RDS(ON) Minimizes Power Losses
- Wettable Flank for Improved Optical Inspection
- Fast Switching Speed
- Low Input Capacitance
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DIODES<sup>™</sup> DMTH45M5LPSWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

## **Mechanical Data**

- Package: PowerDI<sup>®</sup>5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminal Finish Matte Tin Annealed over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208 (€3)
- Weight: 0.097 grams (Approximate)





Top View Pin Configuration

## Ordering Information (Note 4)

Top View

Notes:

Part Number	Backaga	Packing		
Fait Nulliber	Package	Qty.	Carrier	
DMTH45M5LPSWQ-13	PowerDI5060-8 (SWP) (Type UX)	2500	Tape & Reel	

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

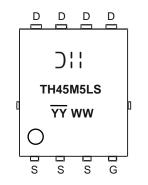
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Pin1

Bottom View



## **Marking Information**



 $\begin{array}{l} \label{eq:thm:stars} \exists TH45M5LS = Product Type Marking Code\\ \hline \underline{YY}WW = Date Code Marking\\ \hline YY = Year Code (ex: 22 = 2022)\\ WW = Week Code (01 to 53) \end{array}$ 

## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V <sub>DSS</sub>	40	V	
Gate-Source Voltage	Vgss	±20	V	
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 5)	Tc = +25°C Tc = +100°C	lo	86 60	А
Maximum Continuous Body Diode Forward Current (Note 5)	ls	86	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	344	A	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		lsм	344	A
Avalanche Current, L = 0.1mH		I <sub>AS</sub>	19.2	A
Avalanche Energy, L = 0.1mH		Eas	18.4	mJ

## **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	T <sub>A</sub> = +25°C	PD	3.5	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R <sub>0JA</sub>	42	°C/W
Total Power Dissipation (Note 5)	Tc = +25°C	PD	72	W
Thermal Resistance, Junction to Case (Note 5)		Rejc	2	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Thermal resistance from junction to soldering point (on the exposed drain pad).

6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.



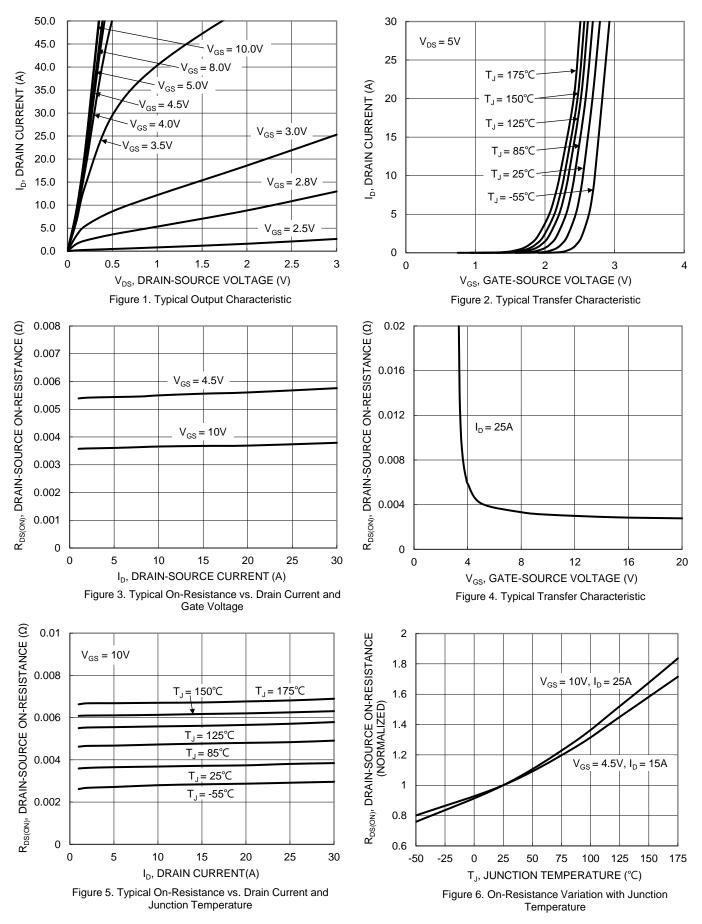
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	40	_	_	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	IDSS	_	—	1	μA	V <sub>DS</sub> = 32V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	lgss	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	1.2	_	2.3	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Preven	_	3.6	5.5		$V_{GS} = 10V, I_D = 25A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	5.4	7.9	mΩ	$V_{GS} = 4.5 V, I_D = 15 A$	
Diode Forward Voltage	Vsd	—	0.82	1.2	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 25A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	—	978	—		$V_{DS} = 20V, V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss	—	630	—	pF		
Reverse Transfer Capacitance	Crss	—	30	—			
Gate Resistance	Rg	—	1.5	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	—	13.9	—		V <sub>DS</sub> = 20V, I <sub>D</sub> = 25A	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	—	6.3	—	nC		
Gate-Source Charge	Qgs	_	3.6	—	ne		
Gate-Drain Charge	Q <sub>gd</sub>	—	0.9	—			
Turn-On Delay Time	td(on)	—	2.8	—		V <sub>GS</sub> = 10V, V <sub>DD</sub> = 20V R <sub>g</sub> = 3.5Ω, I <sub>D</sub> = 25A	
Turn-On Rise Time	tR	_	3.1	—			
Turn-Off Delay Time	tD(OFF)		15.6	_	ns		
Turn-Off Fall Time	t⊨	_	5.5	_			
Body Diode Reverse Recovery Time	t <sub>RR</sub>	_	59	_	ns		
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>		50	_	nC	IF = 25A, dl/dt = 100A/µs	

Notes: 7. Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to product testing.

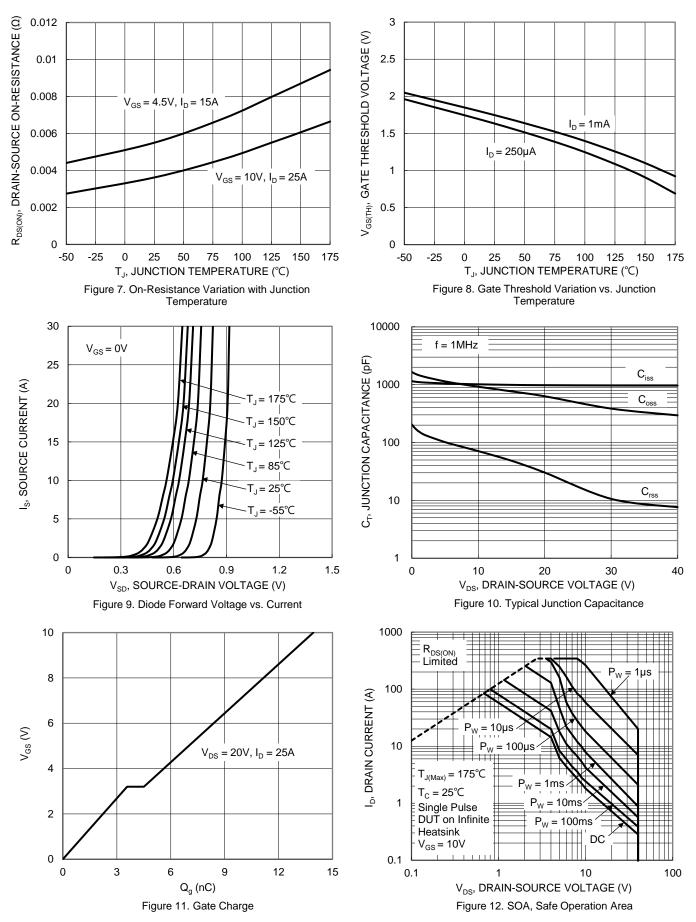


## DMTH45M5LPSWQ



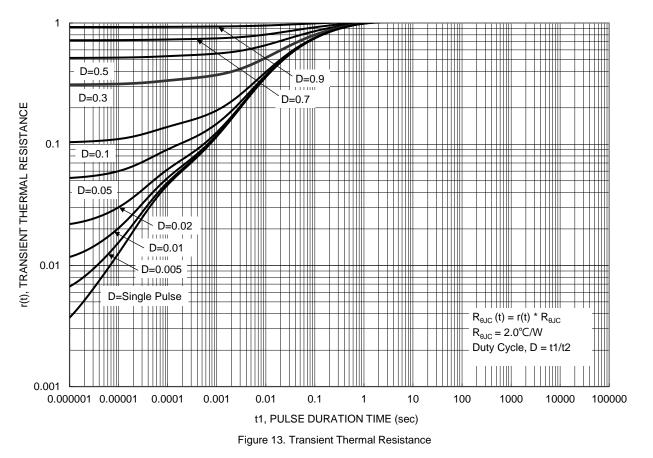


## DMTH45M5LPSWQ



DMTH45M5LPSWQ Document number: DS44402 Rev. 3 - 2





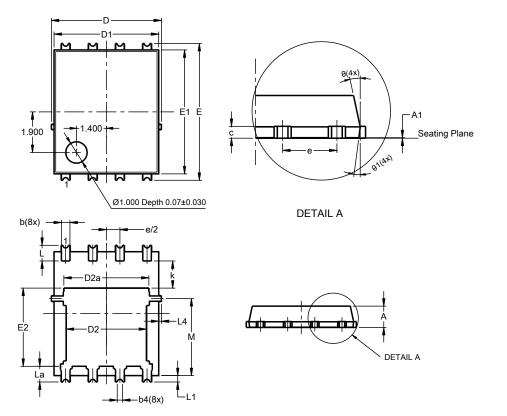


PowerDI5060-8 (SWP)

Γ

## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



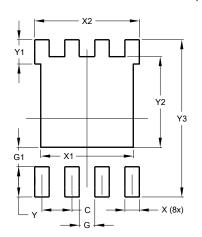
PowerDI5060-8 (SWP) (Type UX)

(Type UX)				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0	0.05		
b	0.30	0.50	0.41	
b2	0.20	0.35	0.25	
b4	(	).25REF	-	
C D	0.230	0.330	0.277	
	5	.15 BS0	2	
D1	4.70	5.10	4.90	
D2	3.56	3.96	3.76	
D2a	3.78	4.18	3.98	
E	6.40 BSC			
E1	5.60	6.00	5.80	
E2	3.46	3.86	3.66	
E2a	4.195	4.595	4.395	
е	1	.27BSC	)	
k	1.05			
L	0.635	0.835	0.735	
La	0.635	0.835	0.735	
L1	0.200	0.400	0.300	
L1a	0	.050RE	F	
L4	0.025	0.225	0.125	
М	3.205	4.005	3.605	
θ	10°	12°	11°	
θ1	6°	8°	7°	
All	All Dimensions in mm			

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### PowerDI5060-8 (SWP) (Type UX)



Dimensions	Value (in mm)		
Dimensions			
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	4.100		
X2	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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